NSN 5961-01-116-6508

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-116-6508 **Inclosure Material:** Metal **Overall Length:** 1.438 inches **Mounting Facility Quantity: Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud Features Provided: Hermetically sealed case **Overall Width Across Flats:** 0.680 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, peak **Current Rating Per Characteristic:** 50.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius ambient air **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0